



Product Summary

BV _{DSS}	R _{DS(on)}	I _D T _A = +25°C
-20V	0.75Ω @ V _{GS} = -4.5V	-1.03A
-200	1.05Ω @ V _{GS} = -2.5V	-0.7A

Description and Applications

This new generation MOSFET is designed to minimize on-state resistance ($R_{DS(on)}$), yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- DC-DC Converters
- Load Switch

Notes:

Power Management Functions

Features and Benefits

- Dual P-Channel MOSFET
- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMG1023UVQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

DUAL P-CHANNEL ENHANCEMENT MODE MOSFET

https://www.diodes.com/guality/product-definitions/

Mechanical Data

- Case: SOT563
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminals: Finish—Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.006 grams (Approximate)



Ordering Information (Note 4)

Part Number	Case	Packaging
DMG1023UVQ-7	SOT563	3,000/Tape & Reel
DMG1023UVQ-13	SOT563	10,000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

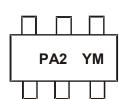
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information



PA2 = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: I = 2021) M = Month (ex: 9 = September)

Date Code Key

Year	2019	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	G	Н		J	K	L	М	Ν	0	Р	R	S
	-											
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec

Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage			V _{DSS}	-20	V
Gate-Source Voltage	V _{GSS}	±6	V		
Continuous Drain Current (Note 5) V _{GS} = -4.5V	I _D	-1.03 -0.68	A		
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	-3	A		

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)	Steady State	PD	0.53	W
Thermal Resistance, Junction to Ambient (Note 5)	$R_{ ext{ heta}JA}$	235	°C/W	
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C	

Note: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.



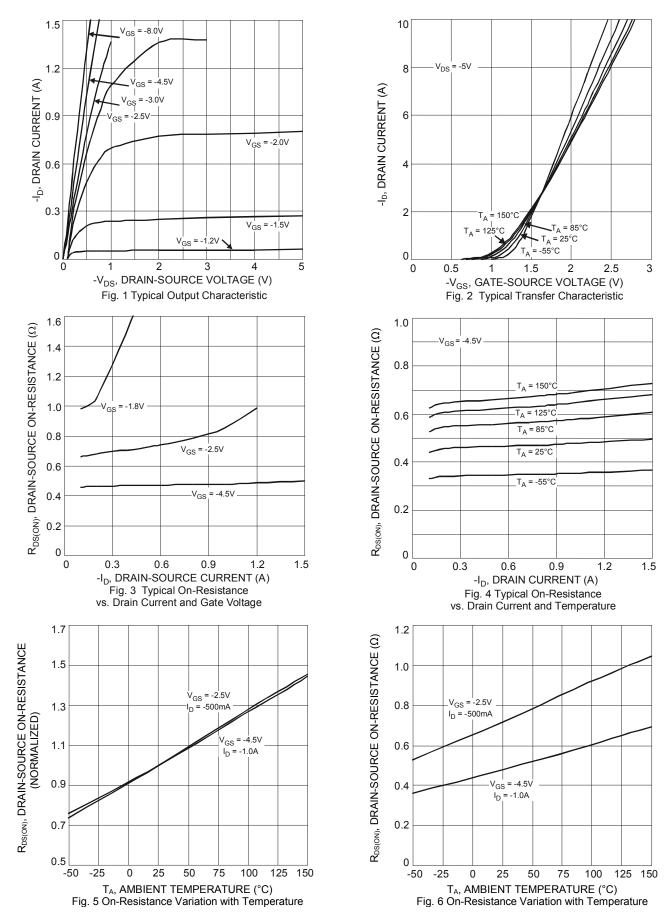
Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)		•		•		
Drain-Source Breakdown Voltage	BV _{DSS}	-20	_	_	V	V _{GS} = 0V, I _D = -250µA
Zero Gate Voltage Drain Current TJ = +25°C	IDSS	—	—	-100	nA	V _{DS} = -20V, V _{GS} = 0V
Gate-Source Leakage	IGSS	—	—	±2.0	μA	V _{GS} = ±4.5V, V _{DS} = 0V
ON CHARACTERISTICS (Note 6)						
Gate Threshold Voltage	V _{GS(th)}	-0.5	-	-1.0	V	V_{DS} = V_{GS} , I_D = -250 μ A
			0.5	0.75		V_{GS} = -4.5V, I_D = -430mA
		_	0.7	1.05		V_{GS} = -2.5V, I _D = -300mA
Static Drain-Source On-Resistance	R _{DS(on)}		1.0	1.5	Ω	V _{GS} = -1.8V, I _D = -150mA
			—	20		V _{GS} = -1.7V, I _D = -100mA
			_	25		V _{GS} = -1.5V, I _D = -100mA
Diode Forward Voltage	V _{SD}	—	-0.8	-1.2	V	V _{GS} = 0V, I _S = -150mA
DYNAMIC CHARACTERISTICS (Note 7)						
Input Capacitance	C _{iss}	_	59	—	pF	
Output Capacitance	C _{oss}	—	12	—	pF	V _{DS} = -16V, V _{GS} = 0V, f = 1.0MHz
Reverse Transfer Capacitance	C _{rss}	—	6.4	—	pF	1 - 1.00012
Total Gate Charge	Qg	—	622	—	рС	
Gate-Source Charge	Q _{gs}	—	100	_	рС	$V_{GS} = -4.5V, V_{DS} = -10V,$
Gate-Drain Charge	Q _{gd}	—	132	—	рС	– I _D = -250mA
Turn-On Delay Time	t _{D(on)}	—	5.1	—	ns	
Turn-On Rise Time	t _R	—	8.1	l —	ns	$V_{DD} = -10V, V_{GS} = -4.5V,$
Turn-Off Delay Time	t _{D(off)}	—	28.4	—	ns	$R_{L} = 47\Omega, R_{G} = 10\Omega,$ $I_{D} = -200 \text{mA}$
Turn-Off Fall Time	t _F	_	20.7	_	ns	- 1020011A

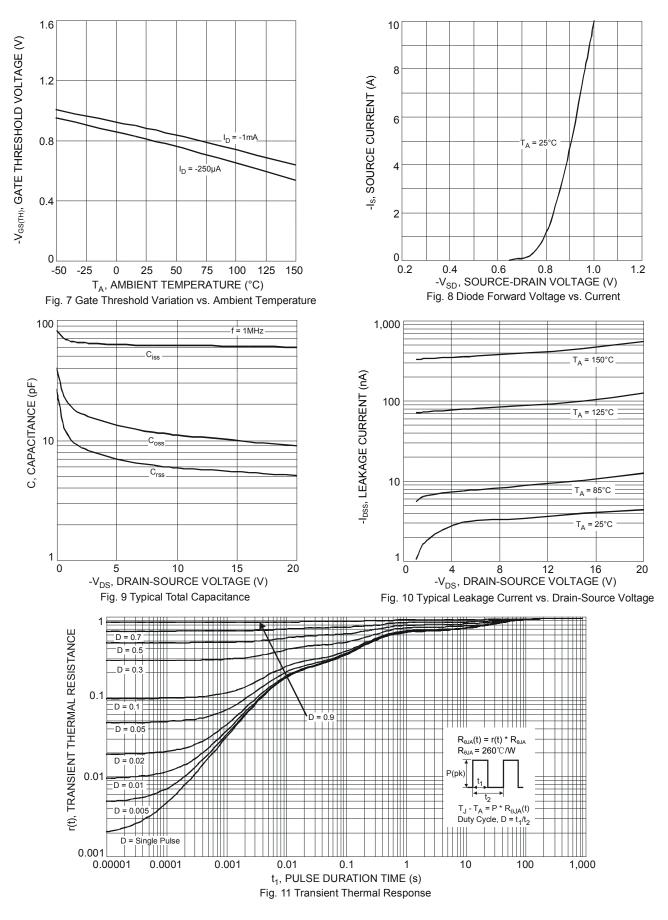
Notes: 6. Short duration pulse test used to minimize self-heating effect.

7. Guaranteed by design. Not subject to production testing.





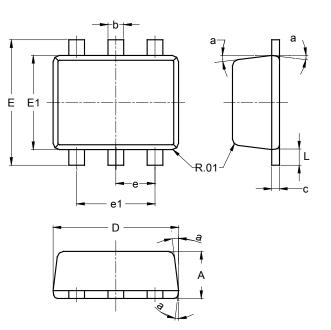






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

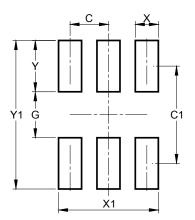


SOT563								
Dim								
A	0.55	0.60	тур					
b	0.15	0.30	0.20					
С	0.10	0.18	0.11					
D	1.50	1.70	1.60					
Е	1.55	1.70	1.60					
E1	1.10	1.25	1.20					
е			0.50					
e1	0.90	1.10	1.00					
L	0.10	0.30	0.20					
а	8°	9°	7°					
All	Dimens	sions in	mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT563



Dimensions	Value (in mm)			
С	0.500			
C1	1.270			
G	0.600			
Х	0.300			
X1	1.300			
Y	0.670			
Y1	1.940			

SOT563



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